

CMOS Digital Integrated Circuits Silicon Monolithic

TC7SB3157DL6X

1. Functional Description

· Single 1-of-2 Multiplexer/Demultiplexer

2. General

The TC7SB3157DL6X is a high-speed CMOS single 1-of-2 multiplexer/demultiplexer. The low ON resistance of the switch allows connections to be made with minimal propagation delay time.

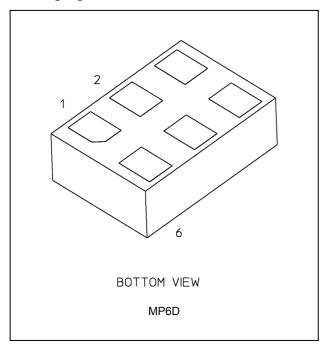
This device is 1 to 2 multiplexer/demultiplexer controlled by the select input (S). The A input is connected to B1 or B2 output based on the selection of Control input (S).

All inputs are equipped with protection circuits against static discharge.

3. Features

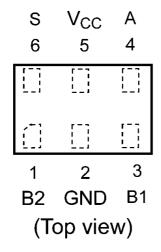
- (1) Operating voltage: $V_{CC} = 1.65$ to 5.5 V
- (2) ON capacitance: $C_{I/O} = 15 \text{ pF Switch On (typ.)} @V_{CC} = 5.0 \text{ V}$
- (3) ON resistance: $R_{\rm ON}$ = 4 Ω (typ.) @V_{\rm CC} = 4.5 V, $V_{\rm IS}$ = 0 V
- (4) Package: MP6D

4. Packaging

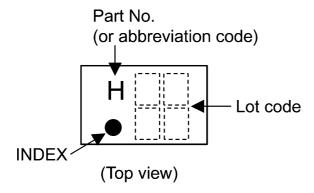




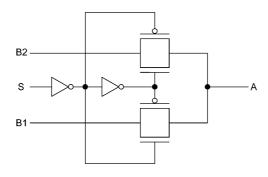
5. Pin Assignment



6. Marking



7. Block Diagram



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8. Principle of Operation

8.1. Truth Table

| Inputs S | Function |
|----------|------------------|
| L | A port = B1 port |
| Н | A port = B2 port |

9. Absolute Maximum Ratings (Note)

| Characteristics | Symbol | Note | Rating | Unit |
|---------------------------------|-----------------------------------|----------|-------------------------|------|
| Supply voltage | V _{CC} | | -0.5 to 6.5 | V |
| Input voltage (S) | V _{IN} | | -0.5 to 6.5 | |
| Switch I/O voltage | Vs | | -0.5 to V _{CC} | |
| Clamp diode current | I _{IK} | | -50 | mA |
| Switch I/O current | I _S | | 50 | |
| Power dissipation | P _D | (Note 1) | 250 | mW |
| V _{CC} /ground current | I _{CC} /I _{GND} | | ±100 | mA |
| Storage temperature | T _{stg} | | -65 to 150 | °C |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on an FR4 board

10. Operating Ranges (Note)

| Characteristics | Symbol | Note | Rating | Unit |
|-----------------------|------------------|------|----------------------|------|
| Supply voltage | V _{CC} | | 1.65 to 5.5 | V |
| Input voltage(S) | V _{IN} | | 0 to 5.5 | |
| Switch I/O voltage | Vs | | 0 to V _{CC} | |
| Operating temperature | T _{opr} | | -40 to 85 | °C |
| Input rise time | dt/dv | | 0 to 10 | ns/V |
| Input fall time | dt/dv | | 0 to 10 | |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused control inputs must be tied to either V_{CC} or GND.



11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

| Characteristics | Symbol | Note | Test Condition | V _{CC} (V) | Min | Тур. | Max | Unit |
|----------------------------------|-----------------|----------|--|---------------------|---------------------|------|---------------------|------|
| High-level input voltage (S) | V_{IH} | | _ | 1.65 to 1.95 | $0.8 \times V_{CC}$ | _ | _ | V |
| | | | | 2.3 to 5.5 | $0.7 \times V_{CC}$ | _ | _ | |
| Low-level input voltage (S) | V _{IL} | | _ | 1.65 to 1.95 | _ | _ | $0.2 \times V_{CC}$ | |
| | | | | 2.3 to 5.5 | _ | _ | $0.3 \times V_{CC}$ | |
| Input leakage current | I _{IN} | | V _{IN} = 0 to 5.5 V | 1.65 to 5.5 | _ | _ | ±1.0 | μА |
| Switch OFF-state leakage current | I _{SZ} | | B1, B2 = 0 to V _{CC} | 1.65 to 5.5 | _ | _ | ±10 | |
| ON-resistance | R _{ON} | | V _{IS} = 0 V, I _{IS} = 30 mA | 4.5 | _ | 4 | 7 | Ω |
| | | (Note 2) | V _{IS} = 2.4 V, I _{IS} = 30 mA | 4.5 | _ | 5 | 12 | |
| | | | V_{IS} = 4.5 V, I_{IS} = 30 mA | 4.5 | | 6 | 10 | |
| | | | V _{IS} = 0 V, I _{IS} = 24 mA | 3.0 | | 5 | 9 | |
| | | | V_{IS} = 3.0 V, I_{IS} = 24 mA | 3.0 | | 7 | 14 | |
| | | | $V_{IS} = 0 \text{ V}, I_{IS} = 8 \text{ mA}$ | 2.3 | | 6 | 12 | |
| | | | V_{IS} = 2.3 V, I_{IS} = 8 mA | 2.3 | | 9 | 18 | |
| | | | $V_{IS} = 0 \text{ V}, I_{IS} = 4 \text{ mA}$ | 1.65 | | 8 | 20 | |
| | | | V_{IS} = 1.65 V, I_{IS} = 4 mA | 1.65 | | 15 | 30 | |
| Quiescent supply current | Icc | | $V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$ A | 5.5 | _ | | 10 | μА |
| | ΔI_{CC} | | $V_{IN} = V_{CC} - 0.6 V$ | 5.5 | _ | _ | 50 | μА |

Note 1: All typical values are at $T_a = 25$ °C.

Note 2: Measured by the voltage drop between A and B pins at the indicated current through the switch. On-resistance is determined by the lower of the voltages on the two (A or B) pins.

11.2. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

| Characteristics | Symbol | Note | Test Condition | V _{CC} (V) | Min | Max | Unit | | | | | | | | |
|-----------------------------|------------------------------------|---------------|--|---------------------|-----|-----|-------------|----------------|---|----|--|--------------|--|----|--|
| 3-state output enable time | t _{PZL} /t _{PZH} | | See Fig. 11.2.1, 11.2.2, Table 11.2.1 | 5.0 ± 0.5 | 1 | 4 | ns | | | | | | | | |
| | | | | 3.3 ± 0.3 | | 6 | | | | | | | | | |
| | | | | 2.5 ± 0.2 | | 8 | | | | | | | | | |
| | | | | | | | | | | | | 1.8 ± 0.15 | | 16 | |
| 3-state output disable time | t _{PLZ} /t _{PHZ} | | See Fig. 11.2.1, 11.2.2, | 5.0 ± 0.5 | | 4.5 | | | | | | | | | |
| Table | Table 11.2.1 | 3.3 ± 0.3 | | 7 | | | | | | | | | | | |
| | | | | | | | 2.5 ± 0.2 | | 9 | | | | | | |
| | | | | | | | | 1.8 ± 0.15 | _ | 16 | | | | | |

11.3. Capacitive Characteristics (Note) (Unless otherwise specified, Ta = 25 °C)

| Characteristics | Symbol | Note | Test Condition | V _{CC} (V) | Тур. | Unit |
|---------------------------------|------------------|------|-------------------------------|---------------------|------|------|
| Input capacitance(S) | C _{IN} | | V _{IN} = 0 V | 5.0 | 4 | pF |
| Switch terminal OFF-capacitance | C _{I/O} | | B Port,V _{I/O} = 0 V | 5.0 | 5 | |
| Switch terminal ON-capacitance | C _{I/O} | | A Port,V _{I/O} = 0 V | 5.0 | 15 | |
| | | | B Port,V _{I/O} = 0 V | 5.0 | 15 | |

Note: Parameter guaranteed by design.



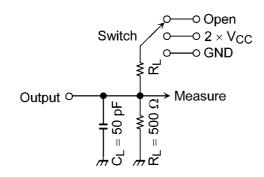


Fig. 11.2.1 AC Test Circuit

Table 11.2.1 Parameter for AC Test Circuit

| Parameter | Switch |
|-------------------------------------|---------------------|
| t _{PLZ} , t _{PZL} | 2 × V _{CC} |
| t _{PHZ} , t _{PZH} | GND |

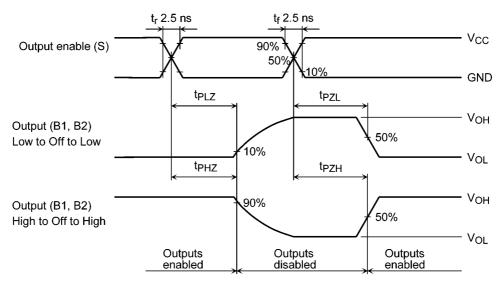


Fig. 11.2.2 AC Waveform t_{PLZ}, t_{PHZ}, t_{PZL}, t_{PZH}

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12. Rise and Fall Time (t_r/t_f)

The $t_{r(out)}$ and $t_{f(out)}$ values of the output signals are affected by the CR time constant of the input, which consists of the switch terminal capacitance (C_{I/O}) and the on-resistance (R_{ON}) of the input.

In practice, the $t_{r(out)}$ and $t_{f(out)}$ values are also affected by the circuit's capacitance and resistance components other than the capacitance of TC7SB3157DL6X

The $t_r/t_{f(out)}$ values can be approximated as follows.

(Figure 12.1, Table 12.1 shows the test circuit.)

$$t_{r}/t_{f(out)} \; (approx) = - \; (C_{I/O} + C_{L}) \; \cdot \; (R_{DRIVE} + R_{ON}) \; \cdot \; ln \; (((V_{OH} - V_{OL}) - V_{M}) \; / \; (V_{OH} - V_{OL})) \; .$$

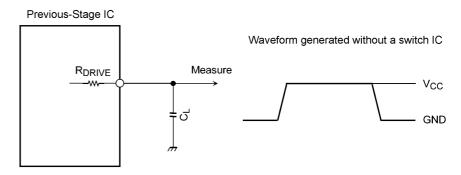
Where, $R_{\mbox{\scriptsize DRIVE}}$ is the output impedance of the previous-stage circuit.

Calculation example:

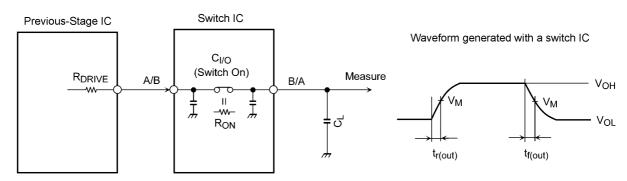
$$t_{r(out)}$$
 (approx) = $-(15 + 15)$ E -12 $+(120 + 4)$ $+\ln(((4.5 - 0) - 2.25) / (4.5 - 0)) = ≈ 2.6 ns$

Calculation conditions:

 $V_{CC} = 4.5 \text{ V}, C_L = 15 \text{ pF}, R_{DRIVE} = 120 \Omega$ (output impedance of the previous IC), $V_M = 2.25 \text{ V}$ ($V_{CC}/2$) Output of the previous IC = digital (i.e., high-level voltage = V_{CC}, low-level voltage = GND)



R_{DRIVE} = output impedance of the previous-stage IC



RDRIVE = output impedance of the previous-stage IC

Calculation Circuit Fig. 12.1

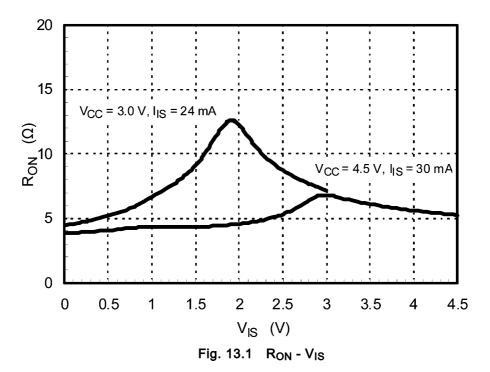
Table 12.1 Calculation Circuit

| Characteristics | V_{CC} = 5.0 \pm 0.5 V | V_{CC} = 3.3 \pm 0.3 V | V_{CC} = 2.5 \pm 0.2 V | V _{CC} = 1.8 ± 0.15 V |
|-----------------|------------------------------|------------------------------|----------------------------|--------------------------------|
| V_{M} | V _{CC} /2 | V _{CC} /2 | V _{CC} /2 | V _{CC} /2 |

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13. Characteristics Curves (Note)

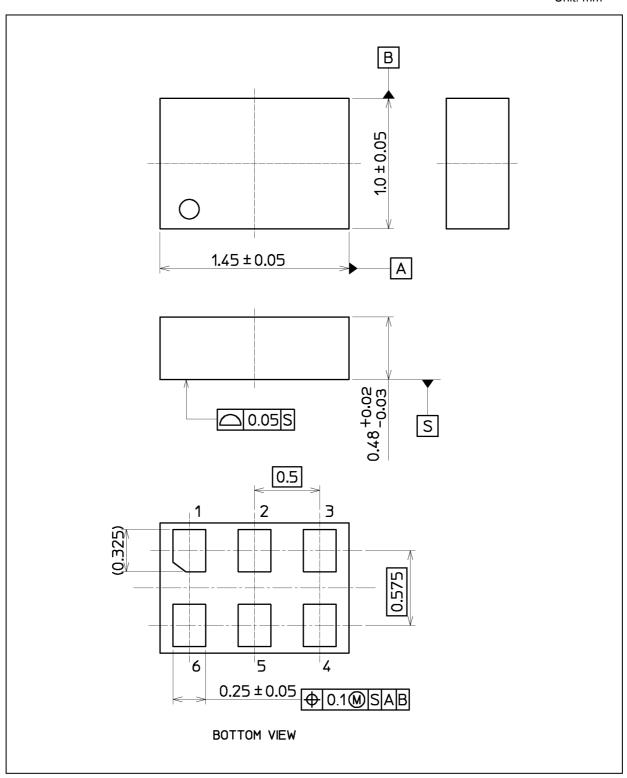


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 0.002 g (typ.)

Package Name(s)
Nickname: MP6D



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